

# SOT23 PNP SILICON PLANAR MEDIUM POWER TRANSISTORS

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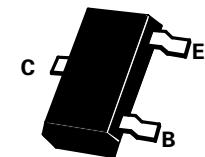
**FMMT549  
FMMT549A**

## FEATURES

- \* Low equivalent on-resistance;  $R_{CE(sat)}$  250mΩ at 1A
- \* 1 Amp continuous current

COMPLEMENTARY TYPES - FMMT549 - FMMT449  
FMMT549A - N/A

PARTMARKING DETAIL - FMMT549 - 549  
FMMT549A - 59A



## ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE		UNIT
Collector-Base Voltage	$V_{CBO}$	-35		V
Collector-Emitter Voltage	$V_{CEO}$	-30		V
Emitter-Base Voltage	$V_{EBO}$	-5		V
Peak Pulse Current	$I_{CM}$	-2		A
Continuous Collector Current	$I_C$	-1		A
Base Current	$I_B$	-200		mA
Power Dissipation: at $T_{amb}=25^\circ\text{C}$	$P_{tot}$	500		mW
Operating and Storage Temperature Range	$T_j \cdot T_{stg}$	-55 to +150		°C

## ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ\text{C}$ unless otherwise stated).

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Breakdown Voltages	$V_{(BR)CBO}$	-35			V	$I_C=100\mu\text{A}$
	$V_{(BR)CEO}$	-30			V	$I_C=10\text{mA}^*$
	$V_{(BR)EBO}$	-5			V	$I_E=100\mu\text{A}$
Cut-Off Currents	$I_{CBO}$			-0.1 -10	$\mu\text{A}$	$V_{CB}=-30\text{V}$ $V_{CB}=-30\text{V}, T_{amb}=100^\circ\text{C}$
	$I_{EBO}$			-0.1	$\mu\text{A}$	$V_{EB}=-4\text{V}$
Saturation Voltages FMMT549A	$V_{CE(sat)}$		-0.25 -0.50	-0.50 -0.75 -0.30	V	$I_C=1\text{A}, I_B=100\text{mA}^*$ $I_C=2\text{A}, I_B=200\text{mA}^*$ $I_C=100\text{mA}, I_B=1\text{mA}^*$
	$V_{BE(sat)}$		-0.9	-1.25	V	$I_C=1\text{A}, I_B=100\text{mA}^*$
Base Emitter Turn-on Voltage	$V_{BE(on)}$		-0.85	-1	V	$I_C=1\text{A}, V_{CE}=-2\text{V}^*$
Static Forward Current Transfer Ratio FMMT549	$h_{FE}$	70 80 40	200 130 80			$I_C=50\text{mA}, V_{CE}=-2\text{V}^*$ $I_C=1\text{A}, V_{CE}=-2\text{V}^*$ $I_C=2\text{A}, V_{CE}=-2\text{V}^*$
		100	160	300		$I_C=500\text{mA}, V_{CE}=-2\text{V}^*$
	FMMT549A	150	200	500		$I_C=500\text{mA}, V_{CE}=-2\text{V}^*$
					MHz	$I_C=100\text{mA}, V_{CE}=-5\text{V}$ $f=100\text{MHz}$
Transition Frequency	$f_T$	100				
Output Capacitance	$C_{obo}$			25	pF	$V_{CE}=-10\text{V}, f=1\text{MHz}$
Switching Times	$t_{on}$		50		ns	$I_C=500\text{mA}, V_{CC}=-10\text{V}$
	$t_{off}$		300		ns	$I_{B1}=I_{B2}=50\text{mA}$

\*Measured under pulsed conditions. Pulse width=300μs. Duty cycle ≤ 2%

# FMMT549

# FMMT549A

## TYPICAL CHARACTERISTICS

